NSN 5962-01-135-9086

Memory Microcircuit - Page 1 of 1



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Body Length:	
0.808 inches	
Body Width:	
0.294 inches	
Body Height:	
0.204 inches	
Maximum Power Dissipatio	n Rating:
332.8 milliwatts	
Operating Tempurature Ra	nge:
+0.0/+75.0 degrees celsius	
Storage Tempurature Rang	le:
-65.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and prog	grammable and bipolar and w/enable
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
6 input	
Voltage Rating And Type P	er Characteristic:
7.0 volts total supply	
Time Rating Per Chacterist	ic:
50.00 nanoseconds propaga	ation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Prom	
Memory Capacity:	
Unknown	
Terminal Type And Quantit	y:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A458a0	